MOBILE ACCESS™—CLOCK SYNTHESIZER, TEMPERATURE SENSOR, & PWM FAN CONTROLLER FOR PORTABLE DEVICES

9TCS1085

Description

The 9TCS1085 is a highly programmable IC that integrates clock synthesizers with a PWM Fan controller and temperature sensor for hardware thermal protection.

The device has an ultra-low-power 32.768 kHz frequency generator to support Real Time Clocks (RTC). This device can generate the 32.768 kHz frequency up to four years of life powered by a CR2032 coin cell battery. The 9TCS1085 can output computer system clock frequencies of 24, 25, 27 and 48 MHz which reduces the component count on the circuit board.

The fan controller is pulsed width modulated (PWM) used for the temperature proportional speed control. The device is highly configurable through I2C for ease and flexibility of use. The fan controller has three different modes of operation and will work with multiple pole, brushless DC fans. An integrated Start-up Timer ensures reliable motor start-up and turn-on or follows a detected fault condition.

The 9TCS1085 includes temperature monitor function that measures an external diode. The temperature sensor is optimized to be accurate within ±1°C between the temperature range of 60°C to 100°C. This device is highly programmable through the use of I^2C to set high and low limits for the temperature sensor. The hardware limits drive dedicated ALERT and THERM pins for system shutdown.

The 9TCS1085 is available in a 32-pin QFN package and is available for commercial temperature range.

Applications

- Notebook Computers
- Netbook Computers
- Smartbook Computers
- Consumer Portable Devices
- Embedded Systems
- Networking Equipment (i.e. Routers, Switches)
- Network Area Storage

Features

Thermal Sensor

- One channel temperature sensor
- Both H/W & S/W programmable over/under temperature alarms
- No Calibration required in application
- Diode failure detection
- Support SMBUS Alert
- Accuracy: ±1°C (+60°C to +100°C); ±2°C (0°C to + 100°C)
- Offset register for system calibration
- Series resistor cancellation feature

Fan Controller

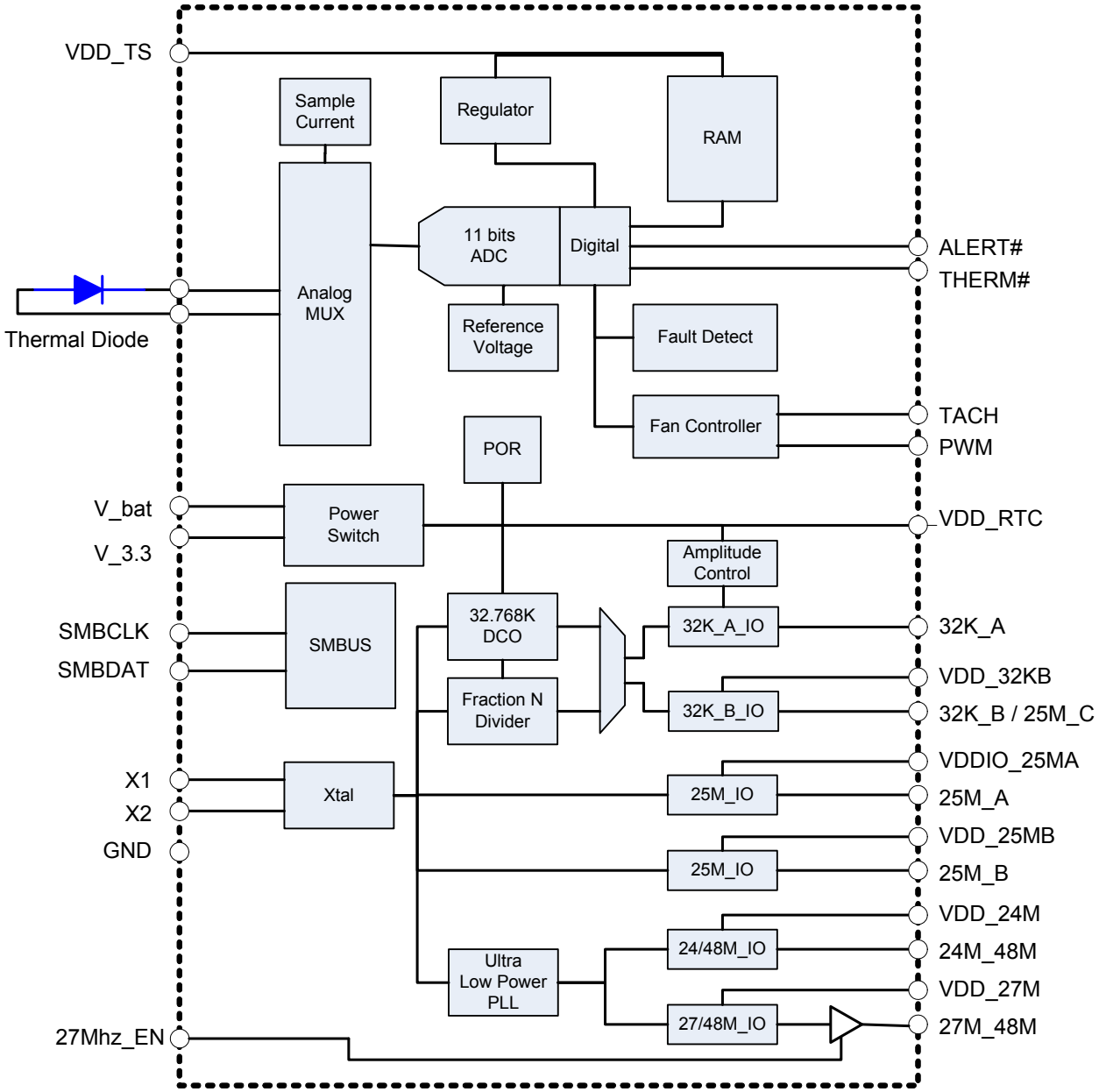
- High frequency or low frequency PWM outputs for use with 4-wire fans
- TACH inputs to measure fan speed
- OS independent automatic fan speed control based on thermal information
- Dynamic TMIN control mode to optimize system acoustics
- Default startup at 100% PWM for all fans for robust operation

System Clock PLL Synthesizers

- Scalable low voltage VDD I/O (1.5V to 1.05V) to reduce power consumption (applies to 25MHz output)
- Integrated series termination resistors
- Selectable – Single-ended 24MHz/27MHz/48MHz clock output @ VDD3.3V
- 3 – Single ended 25MHz clock outputs (buffer out)
- 32.768 kHz outputs with < 1.8µA power consumption for system RTC circuit

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Block Diagram

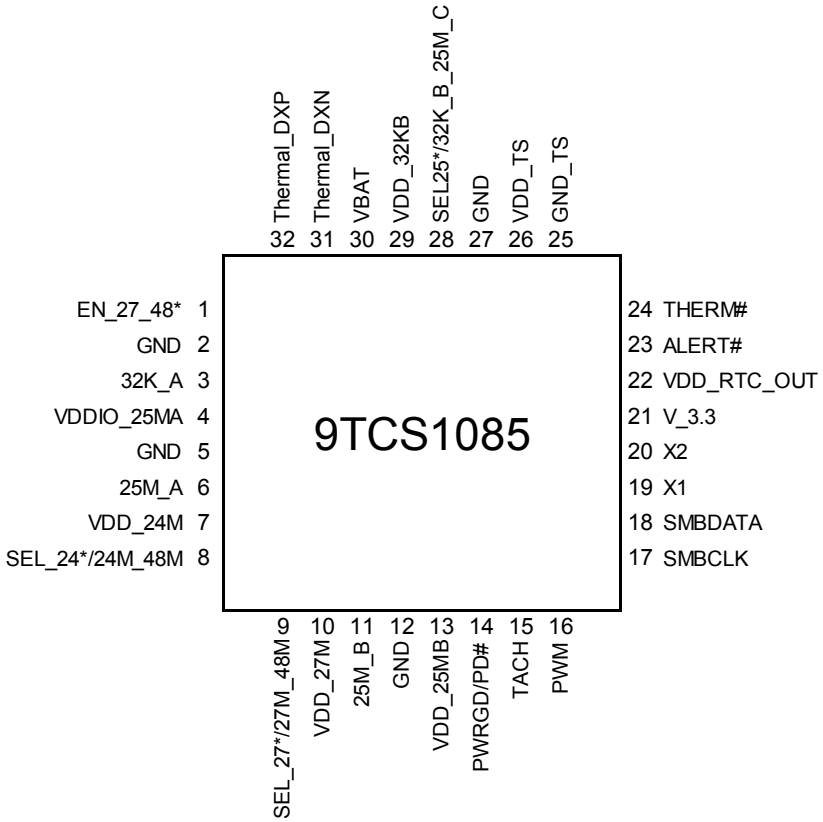


Preferred drive strengths for single-ended outputs.
Transmission lines to load do not share series resistors.
Desktop (Zo=50Ω) and mobile (Zo=55Ω) have the same drive strength.

	Number of Loads to Drive	Match Point for N & P Voltage / Current (mA)	Number of Loads Actually Driven.		
			1 Load Rs =	2 Loads Rs=	3 Loads Rs =
D.C.Drive Strength	1	0.56 / 33 (17Ω)	33Ω [39Ω]	-	-
	2	0.92 / 66 (14Ω)	39Ω [43Ω]	22Ω [27Ω]	-
	3	1.15 / 99 (11.6Ω)	43Ω [43Ω]	27Ω [33Ω]	15Ω [22Ω]

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Pin Assignment



* Internal Pull-Up Resistor
24M/27M/48Mhz outputs require external series resistors on Board.

Power Group

Pin Number		Description
VDD	GND	
4	2	VDDIO_25MA IO power
7	5	VDD_24M power
10	12	VDD_27M power
13	2	VDD_25B Power
21	2	V_3.3 core power
22	27	VDD_RTC_Out
26	25	VDD_TS power
29	27	VDD_32KB Power
30	27	V_bat for DCO and 32KA power

* pin33: thermal pad

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Pin Descriptions

PIN	PIN NAME	TYPE	DESCRIPTION
1	EN_27_48*	PWR	Pin10 27_48 output enable/disable. Real time
2	GND	OUT	Ground pin
3	32K_A	OUT	RTC clock 32.768KHz output A
4	VDDIO_25MA	PWR	Power for 25MHz_A output
5	GND	PWR	Ground pin
6	25M_A	OUT	25MHz_A Output
7	VDD_24M	PWR	Power for 24/48 MHz output
8	SEL_24*/24M_48M	I/O	24Mhz Enable Latched Input, programmable Free Running 24/48M clock output. SEL_24 Selects the functionality of the 24_48M output as follows: 1 = 24M output (Default) 0 = 48M output
9	SEL_27*/27M_48M	I/O	27Mhz Enable Latched Input, programmable Free Running 27/48M clock output. SEL_27 Selects the functionality of the 27_48M output as follows: 1 = 27M output (default) 0 = 48M output
10	VDD_27M	PWR	Power for 27/48 MHz output
11	25M_B	OUT	25MHz_B Output
12	GND	PWR	Ground pin
13	VDD_25MB	PWR	Power for LDO and main circuit
14	PWRGD/PD#	IN	This 3.3V LVTTL input notifies device to sample latched inputs and start up on first high assertion, or
15	TACH	IN	Fan controller TACH signal input
16	PWM	OUT	Fan controller PWM signal output
17	SMBCLK	IN	SMBUS clock
18	SMBDAT	I/O	SMBUS data
19	X1	IN	Crystal input, Nominally25MHz.
20	X2	OUT	Crystal output, Nominally 25MHz
21	V_3.3	PWR	Power for 32K PLL core, connect to system 3.3V_StandBy
22	VDD_RTC_OUT	OUT	Power for chipset RTC circuit
23	ALERT#	OUT	open drain interrupt output for SMBUS Alert pin
24	THERM#	OUT	open drain interrupt output for external hardware connection
25	GND_TS	PWR	Ground pin for thermal sensor function
26	VDD_TS	PWR	Power for thermal sensor function
27	GND	PWR	Ground pin
28	SEL_25*/32KB_25M_C	I/O	25Mhz_C output select pin, programmable Free Running 32.768Khz or 25Mhz clock output. SEL_25* Selects the functionality of the 32K_25M output as follows: 1 = 25Mhz output (Default) 0 = 32.768Khz output
29	VDD_32KB	PWR	Power for 32.768Khz_B output
30	VBAT	PWR	Power for 32kHz_A output. Connect to coin cell battery
31	Thermal_DXN1	IN	external thermal diode N
32	Thermal_DXP1	IN	external thermal diode P
33	Thermal Pad	PWR	GND

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Frequency and Output Selection Tables

Clock Output Selection Table

Pin number	Setting	Output	Remark
8	L	48MHz	
	H	24MHz	default, internal pull high
9	L	48MHz	
	H	27MHz	default, internal pull high
28	L	32.768KHz_B	
	H	25MHz_C	default, internal pull high

Output Selection Table A

Power Supply		VDDIO_Control			Outputs				
V_Bat	V_3.3	VDD_32KB	VDDIO_25A	VDD_25B	32K_A	32K_B	25M_A	25M_B	VDD_RTC
2.3~3.0	0	0	0	0	ON	OFF	OFF	OFF	Vbat
2.3~3.0	3.3[1]	0	0	0	ON	OFF	OFF	OFF	V3.3
2.3~3.0	3.3[1]	3.3	0	0	ON	ON	OFF	OFF	V3.3
2.3~3.0	3.3[1]	3.3	1.05~1.5[2]	0	ON	ON	ON	OFF	V3.3
2.3~3.0	3.3[1]	3.3	1.05~1.5[2]	3.3	ON	ON	ON	ON	V3.3

Note 1: When V3.3 is applied, XTAL will always be ON. 32K source will switch to an analog PLL. Fan control will be ON.
Note 2: If amplitude greater than 1.5V is required on 25MHz_A output, please contact IDT support.

Output Selection Table B

Power Supply				Outputs			
V_3.3	VDD_24M[1]	VDD_27M	VDD_TS	24_48M	27_48M	Fan Control	Thermal Sensor
3.3	0	0	0	OFF	OFF	ON	OFF
3.3	3.3	0	0	ON	OFF	ON	OFF
3.3	3.3	3.3	0	ON	ON	ON	OFF
3.3	3.3	3.3	3.3	ON	ON	ON	ON

Note 1: When either VDD_24M, VDD_27M or VDD_TS is ON, V_3.3 should be ON.

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Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9TCS1085. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
Maximum Supply Voltage	VDDxxx	Core/Logic Supply		3.6	V	1,2
Maximum Supply Voltage	VDDIOxxx	Core/Logic Supply		3.6	V	1,2
Maximum Input Voltage	V_{IH}	3.3V LVCMOS Inputs		3.6	V	1,2,3
Minimum Input Voltage	V_{IL}	Any Input	GND - 0.5		V	1,2
Storage Temperature	Ts	-	-65	150	°C	1,2
Case Temperature	Tcase	-		115	°C	1,2

[1] Unless otherwise noted, guaranteed by design and characterization, not 100% tested in production.

[2] Operation under these conditions is neither implied, nor guaranteed.

[3] Maximum input voltage is not to exceed maximum VDD

Electrical Characteristics–SMBus Interface

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
SMBus Voltage	V_{DD}		2.7	3.6	V	1
Low-level Output Voltage	V_{OLSMB}	@ I_{PULLUP}		0.4	V	1
Current sinking at V_{OLSMB} = 0.4 V	I_{PULLUP}	SMB Data Pin	4		mA	1
SCLK/SDATA Clock/Data Rise Time	T_{RI2C}	(Max VIL - 0.15) to (Min VIH + 0.15)		1000	ns	1
SCLK/SDATA Clock/Data Fall Time	T_{FI2C}	(Min VIH + 0.15) to (Max VIL - 0.15)		300	ns	1
Maximum SMBus Operating Frequency	F_{SMBUS}	Block Mode		400	kHz	1

[1] Unless otherwise noted, guaranteed by design and characterization, not 100% tested in production.

AC Electrical Characteristics–Input/Common Parameters

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
Clk Stabilization	T_{STAB}	From VDD Power-Up or de-assertion of PD# to 1st clock		1.8	ms	1
Tdrive_PD#	T_{DRPD}	Differential output enable after PD# de-assertion		300	us	1

[1] Unless otherwise noted, guaranteed by design and characterization, not 100% tested in production.

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Electrical Characteristics–Input/Supply/Common Parameters

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
Ambient Operating Temp	Tambient	-	0	70	°C	
Supply Voltage	V_3.3	Supply Voltage	3.135	3.465	V	
Supply Voltage	VDD_xx	Other Supply Voltages	3.135	3.465	V	
Supply Voltage	VDDIO_25MA	Supply Voltage	0.9975	1.575	V	
Supply Voltage	V_bat	Supply Voltage	2.3	3.465	V	
Input High Voltage	V_{IHSE}	Single-ended inputs	2	V_{DD} + 0.3	V	1,4
Input Low Voltage	V_{ILSE}	Single-ended inputs	V_{SS} - 0.3	0.8	V	1,4
Low Threshold Input-High Voltage	V_{IH_FS}	3.3 V +/-5%	0.7	V_{DD} + 0.3	V	1
Low Threshold Input-Low Voltage	V_{IL_FS}	3.3 V +/-5%	V_{SS} - 0.3	0.35	V	1
Input Leakage Current	I_{IN}	$V_{IN} = V_{DD}$, V_{IN} = GND	-5	5	uA	1,3
Input Leakage Current	I_{INRES}	Inputs with pull or pull down resistors $V_{IN} = V_{DD}$, V_{IN} = GND	-200	200	uA	1
Output High Voltage	V_{OHSE}	Single-ended outputs, I_{OH} = -1mA	2.4		V	1,2
Output Low Voltage	V_{OLSE}	Single-ended outputs, I_{OL} = 1 mA		0.4	V	1,2
3.3V Operating Supply Current	$I_{DD3.3OP}$	Full active mode, C_L = Full load, 3.3V Rail		50	mA	1
	$I_{DD3.3PD\#}$	Complete Power-Down, 3.3V Rail		10	mA	1
	$I_{DD3.3WOL}$	WOL Mode with 25MA running, 3.3V Rail		25	mA	1
	$I_{DD3.3RTC}$	RTC Mode with 32KA running, 3.3V Rail		0.1	uA	1
VDDIO Operating Supply Current	I_{DDIO_OP}	Full active mode, C_L = Full load, VDDIO Rails		5	mA	1
	$I_{DDIO_PD\#}$	Complete Power-Down, VDDIO Rails		1	mA	1
	I_{DDDIO_WOL}	WOL Mode with 25MA running, VDDIO Rails		10	mA	1
	I_{DDIO_RTC}	RTC Mode with only 32KA running, VDDIO Rails		0.5	uA	1
V_bat Operating Supply Current	IDD_V_bat	RTC Mode with 32KA running, V_bat Rail		1.8	uA	1
Input Frequency	F_i	V_{DD} = 3.3 V	25MHz Typical		MHz	1
Pin Inductance	L_{pin}			7	nH	1
Input Capacitance	C_{IN}	Logic Inputs	1.5	5	pF	1
	C_{OUT}	Output pin capacitance		6	pF	1
	C_{INX}	X1 & X2 pins		6	pF	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 5pF with Rs = 27Ω (unless otherwise specified)

[1] Unless otherwise noted, guaranteed by design and characterization, not 100% tested in production.

[2]Signal is required to be monotonic in this region.

[3] Input leakage current does not include inputs with pull-up or pull-down resistors

[4] 3.3V referenced inputs are: SCLK, SDATA, SEL_25, SEL_24, SEL_27, PWRGD.

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AC Electrical Characteristics–Power Management

Output Clock Power Consumption Table

Power Supply		Power Consumption @ 2' transmission line			
V_bat / V_3.3	Outputs	I_V_bat	I_V_3.3	I_VDD_32KB	I_VDD_25M
2.3~3.3	32K_A	1.8uA	0	0	0
2.3~3.3	32K_A	0	2mA	0	0
2.3~3.3	32K_A+B	0	2mA	1uA	0
2.3~3.3	32K, 25M_A	0	2mA	1uA	1mA
2.3~3.3	32K_A+B,25MA+B	0	2mA	1uA	2mA

Note: When V_3.3 is applied, XTAL will always be ON. 32K source will switch to an analog PLL.

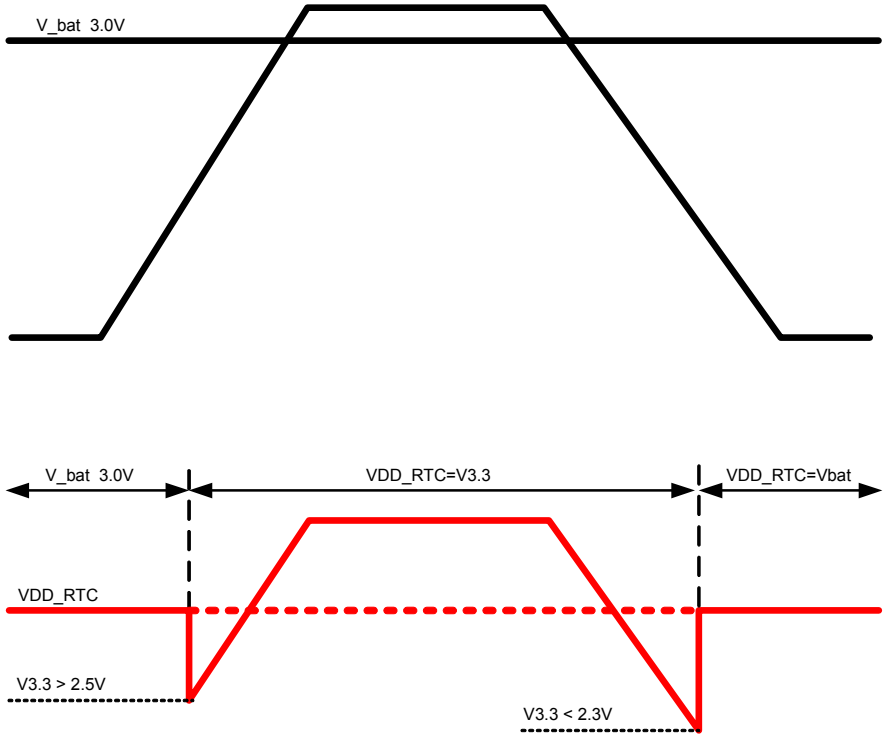
Power Supply		Power consumption @ 2' transmission line			
V_3.3	VDD_24/27/TS	I_V3.3	I_VDD_24M	I_VDD_27M	I_VDD_TS
3.3	0	2mA	0	0	0
3.3	24Mhz	2mA	3mA	0	0
3.3	24/27Mhz	2mA	3mA	1mA	0
3.3	24/27Mhz+Thermal+Fan	2mA	3mA	1mA	0.8mA

Note: When either VDD_24M, VDD_27M or VDD_TS is ON, V3.3 should be ON

Power Switch (VBAT/V33 -> VDD_RTC)

Integrated power switch detects the VDD_RTC SW to coin cell battery (VBAT) or main power supply (V33).

When there is no V33 (V33=0), the SW will connect the VDD_RTC to VBAT; when V33 goes higher than 2.5V, the VDD_RTC will be switched to V33 with no delay. After V33 goes lower than 2.3V, the VDD_RTC will be switched to VBAT, no delay.



When VDD_RTC = VBAT, the power SW circuit consumes < 100nA.

When VDD_RTC = V33, the power consumption on VBAT needs to be “0”.

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Electrical Characteristics–USB48MHz

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	NOTES
Long Accuracy	ppm	see Tperiod min-max values	-100	100	ppm	1,2
Clock period	T_{period}	48.00MHz output nominal	20.8313	20.8354	ns	1,2
Output High Voltage	V_{OH}	I_{OH} = -1 mA	2.4		V	1
Output Low Voltage	V_{OL}	I_{OL} = 1 mA		0.4	V	1
Output High Current	I_{OH}	V_{OH} @MIN = 1.0 V	-33		mA	1
		V_{OH}@MAX = 3.135 V		-33	mA	1
Output Low Current	I_{OL}	V_{OL} @ MIN = 1.95 V	30		mA	1
		V_{OL} @ MAX = 0.4 V		38	mA	1
Rising Edge Slew Rate	t_{SLR}	Measured from 0.8 to 2.0 V	0.5	2.5	V/ns	1
Falling Edge Slew Rate	t_{SLR}	Measured from 2.0 to 0.8 V	0.5	2.5	V/ns	1
Duty Cycle	d_{t1}	V_T = 1.5 V	45	55	%	1
Jitter, Cycle to cycle	$t_{jcyc-cyc}$	V_T = 1.5 V		350	ps	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 5pF with Rs = 27Ω (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REFOUT is at 25.000000MHz

Electrical Characteristics–24MHz

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	NOTES
Long Accuracy	ppm	see Tperiod min-max values	-100	100	ppm	1,2
Clock period	T_{period}	24.00MHz output nominal	41.6625	41.6708	ns	1,2
Output High Voltage	V_{OH}	I_{OH} = -1 mA	2.4		V	1
Output Low Voltage	V_{OL}	I_{OL} = 1 mA		0.4	V	1
Output High Current	I_{OH}	V_{OH} @MIN = 1.0 V	-33		mA	1
		V_{OH}@MAX = 3.135 V		-33	mA	1
Output Low Current	I_{OL}	V_{OL} @ MIN = 1.95 V	30		mA	1
		V_{OL} @ MAX = 0.4 V		38	mA	1
Rising Edge Slew Rate	t_{SLR}	Measured from 0.8 to 2.0 V	0.5	4	V/ns	1
Falling Edge Slew Rate	t_{SLR}	Measured from 2.0 to 0.8 V	0.5	4	V/ns	1
Duty Cycle	d_{t1}	V_T = 1.5 V	45	55	%	1
Jitter, Cycle to cycle	$t_{jcyc-cyc}$	V_T = 1.5 V		350	ps	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 5pF with Rs = 27Ω (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REFOUT is at 25.000000MHz

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Electrical Characteristics–25MHz

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	NOTES
Long Accuracy	ppm	see Tperiod min-max values	-100	100	ppm	1,2
Clock period	T_{period}	25.00MHz output nominal	39.99600	40.00400	ns	1,2
Output High Voltage	V_{OH}	I_{OH} = -1 mA	2.4		V	1
Output Low Voltage	V_{OL}	I_{OL} = 1 mA		0.4	V	1
Output High Current	I_{OH}	V_{OH} @MIN = 1.0 V	-29		mA	1
		V_{OH}@MAX = 3.135 V		-23	mA	1
Output Low Current	I_{OL}	V_{OL} @ MIN = 1.95 V	29		mA	1
		V_{OL} @ MAX = 0.4 V		27	mA	1
Rising Edge Slew Rate	t_{SLR}	Measured from 0.8 to 2.0 V	0.5	4	V/ns	1
Falling Edge Slew Rate	t_{SLR}	Measured from 2.0 to 0.8 V	0.5	4	V/ns	1
Duty Cycle	d_{t1}	V_T = 1.5 V	40	60	%	1
Jitter, Cycle to cycle	$t_{jcyc-cyc}$	V_T = 1.5 V		500	ps	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 5pF with Rs =0Ω (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REFOUT is at 25.000000MHz

Electrical Characteristics–27MHz

Long Accuracy	ppm	see Tperiod min-max values	-50	50	ppm	1,2
Clock period	T_{period}	27.000MHz output nominal	37.0365	37.0376	ns	1,2
Output High Voltage	V_{OH}	I_{OH} = -1 mA	2.4		V	1
Output Low Voltage	V_{OL}	I_{OL} = 1 mA		0.4	V	1
Output High Current	I_{OH}	V_{OH} @MIN = 1.0 V	-29		mA	1
		V_{OH}@MAX = 3.135 V		-23	mA	1
Output Low Current	I_{OL}	V_{OL} @ MIN = 1.95 V	29		mA	1
		V_{OL} @ MAX = 0.4 V		27	mA	1
Rising Edge Slew Rate	t_{SLR}	Measured from 0.8 to 2.0 V	1	4	V/ns	1
Falling Edge Slew Rate	t_{FLR}	Measured from 2.0 to 0.8 V	1	4	V/ns	1
Duty Cycle	d_{t1}	V_T = 1.5 V	45	55	%	1
Jitter, Cycle to cycle	$t_{jcyc-cyc}$	Cycle to Cycle, V_T = 1.5 V		200	ps	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 5pF with Rs = 27Ω (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REFOUT is at 25.000000MHz

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Electrical Characteristics–32KHz_A (Low Voltage Output)

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
Long Accuracy	ppm	see Tperiod min-max values	32.768 Typical		kHz	1,2
Output High Voltage	V_{OH}	32K_A Output	0.8	1.2	V	1
Output Low Voltage	V_{OL}	32K_A Output		0.3	V	1
Initial Frequency Error	$32K_{INI}$	0C to 70C		+/-10	ppm	1
				0.86	sec/day	1
RTC Frequency Error	$32K_{RTC_7D}$	7-day measurement		8	sec	1
Rising Edge Slew Rate	t_{SLR}	Measured from 20% to 80%	0.03 typ		V/ns	1
Falling Edge Slew Rate	t_{FLR}	Measured from 80% to 20%	0.03 typ		V/ns	1
Duty Cycle	d_{t1}	VT = V_bat/2	40	60	%	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 2pF with Rs = 0Ω (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REFOUT is at 25.000000MHz

Electrical Characteristics–32KHz_B

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
Long Accuracy	ppm	see Tperiod min-max values	32.768 Typical		kHz	1,2
Output High Voltage	V_{OH}	32K_B Output	0.9975	3.465	V	1
Output Low Voltage	V_{OL}	32K_B Output		0.3	V	1
Initial Frequency Error	$32K_{INI}$	0C to 70C		+/-10	ppm	1
				0.86	sec/day	1
Rising Edge Slew Rate	t_{SLR}	Measured from 20% to 80%	0.3	2	V/ns	1
Falling Edge Slew Rate	t_{FLR}	Measured from 80% to 20%	0.3	2	V/ns	1
Duty Cycle	d_{t1}	VT = V_bat/2	40	60	%	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5%, CL = 2pF with Rs = 0Ω (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REFOUT is at 25.000000MHz

Recommended 25MHz Crystal Specification

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	NOTES
Frequency Accuracy	Faccur	@25C		+/-10	ppm	1
Frequency Error over temperature	Ferrt	-10C ~ 70C		+/-10	ppm	1
Frequency Aging	Faging	1 year		+/-1	ppm	1
Driver Level	DL			100	uW	1
Crystal Load Capacitance	CL	Parallel Resonance	8pF Typical		pF	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5% (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

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Electrical Characteristics–Thermal Sensor Controller

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
Local Sensor Accuracy		0C<TA<60C		2	C	1
		60C<TA<100C		1	C	1
Resolution				1	C	1
Remote Sensor Accuracy	Raccu	0C<TA<60C		2	C	1
		60C<TA<100C		1	C	1
Resolution	Rs			1	C	1
Conversion Rate	CR		16	1/64	Sec	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5% (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics–Fan Controller

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS	Notes
PWM frequency	PWM		25	27	kHz	1
PWM Duty Cycle	DUTY			100	%	1
Tachometer Range	TACH		1	4	POLE	1

*TA = 0 - 70°C; Supply Voltage V_3.3 = VDD_TS = 3.3 V +/-5%, VDD_24M = VDD_27M = VDD_25MB = 3.3V +/- 5%, VDD_25MA = 1.05V +/- 5%, VDD_32KB = 3.3V +/- 5% (unless otherwise specified)

[1]Guaranteed by design and characterization, not 100% tested in production.

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General SMBus Serial Interface Information for 9TCS1085

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will **acknowledge**
- Controller (host) starts sending Byte **N through Byte N+X-1**
- IDT clock will **acknowledg**e each byte **one at a time**
- Controller (host) sends a Stop bit

Index Block Write Operation			
Controller (Host)			**IDT (Slave/Receiver)**
T	starT bit		
Slave Address			
WR	WRite		
			ACK
Beginning Byte = N			
			ACK
Data Byte Count = X			
			ACK
Beginning Byte N		X Byte	
			ACK
O			
O			O
O			O
			O
Byte N + X - 1			
			ACK
P	stoP bit		

Read Address	Write Address
$D3_{H)}$	$D2_{(H)}$

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will **acknowledge**
- IDT clock will send the data byte count = X
- IDT clock sends Byte **N+X-1**
- IDT clock sends **Byte 0 through Byte X (if $X_{(H)}$ was written to Byte 8)**
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Index Block Read Operation			
Controller (Host)			**IDT (Slave/Receiver)**
T	starT bit		
Slave Address			
WR	WRite		
			ACK
Beginning Byte = N			
			ACK
RT	Repeat starT		
Slave Address			
RD	ReaD		
			ACK
			Data Byte Count=X
ACK			
		X Byte	Beginning Byte N
ACK			
			O
O			O
O			O
O			
			Byte N + X - 1
N	Not acknowledge		
P	stoP bit		

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Byte0	Name	Control Function	Type	0	1	PWD
Bit7	ALERT_TH1	CH1 Diode ALERT High Temperature Limit	RW	-	SIGN	0
Bit6					64C	1
Bit5					32C	1
Bit4					16C	1
Bit3					8C	1
Bit2					4C	1
Bit1					2C	1
Bit0					1C	1

Note: Register readback uses 2's Complement

Byte1	Name	Control Function	Type	0	1	PWD
Bit7	Reserved	Reserved	RW	-	-	0
Bit6					-	1
Bit5					-	1
Bit4					-	1
Bit3					-	1
Bit2					-	1
Bit1					-	1
Bit0					-	1

Note: Register readback uses 2's Complement

Byte 2 Reserved Register

Byte3	Name	Control Function	Type	0	1	PWD
Bit7	ALERT_TL1	CH1 Diode ALERT Low Temperature Limit	RW	-	SIGN	1
Bit6					64C	0
Bit5					32C	0
Bit4					16C	0
Bit3					8C	0
Bit2					4C	0
Bit1					2C	0
Bit0					1C	1

Note: Register readback uses 2's Complement

Byte 4~5 Reserved Register

Byte6	Name	Control Function	Type	0	1	PWD
Bit7	CH1_EN	Enable Temp-Sensor Channel1	RW	Disable	Enable	0
Bit6	Reserved	Reserved	RW	-	-	0
Bit5	Reserved	Reserved	RW	-	-	1
Bit4	Reserved	Reserved	RW	-	-	0
Bit3	Consecutive ALERT	Consecutive ALERT Report	RW	00 = 1	01 = 2	0
Bit2			RW	10 = 3	11 = 4	0
Bit1	Average_Fact	Average the converted temperature	RW	00 = 1	01 = 4	0
Bit0			RW	10 = 8	11 = 16	0

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Byte7	Name	Control Function	Type	0	1	PWD
Bit7	THERMAL1	CH1 Diode THERMALTemperature Limit	RW	-	Reserved	0
Bit6					64C	1
Bit5					32C	1
Bit4					16C	1
Bit3					8C	1
Bit2					4C	1
Bit1					2C	1
Bit0					1C	1

Byte 8~9 Reserved Register

Byte10	Name	Control Function	Type	0	1	PWD
Bit7	D_A1	CH1 Gain (Slope) Coefficient	RW	-	1.28C	1
Bit6			RW		0.64C	0
Bit5			RW		0.32C	0
Bit4			RW		0.16C	0
Bit3	D_B1	CH1 Offset Coefficient	RW		4C	1
Bit2			RW		2C	0
Bit1			RW		1C	0
Bit0			RW		0.5C	0

Byte 11 Reserved Register

Byte12	Name	Control Function	Type	0	1	PWD
Bit7	Reserved	Reserved	RW	-	-	0
Bit6	Reserved	Reserved	RW	-	-	0
Bit5	MASK1	MASK Channel1 ALERT	RW	Non-Mask	Mask	0
Bit4	THERMAL_HYS	THERMAL Limit Hysteresis	RW	-	16C	0
Bit3			RW		8C	0
Bit2			RW		4C	1
Bit1			RW		2C	0
Bit0			RW		1C	0

Byte13	Name	Control Function	Type	0	1	PWD
Bit7	Reserved	Reserved	R	-	-	0
Bit6	Reserved	Reserved	R	-	-	0
Bit5	Reserved	Reserved	R	-	-	0
Bit4	Reserved	Reserved	R	-	-	0
Bit3	CH1 High	Channel 1 ALERT High Alarm	R	Non-Flag	Flag	0
Bit2	CH1 Low	Channel 1 ALERT Low Alarm	R	Non-Flag	Flag	0
Bit1	CH1 Fault	Channel 1 Diode Fault (Open)	R	Non-Flag	Flag	0
Bit0	Reserved	Reserved	R	-	-	0

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Byte14	Name	Control Function	Type	0	1	PWD
Bit7	BUSY	ADC is converting	R	Non-Flag	Flag	0
Bit6	HIGH	One of the Channels ALERT High	R	Non-Flag	Flag	0
Bit5	LOW	One of the Channels ALERT Low	R	Non-Flag	Flag	0
Bit4	FAULT	One of the EXT-Channel Open/Short	R	Non-Flag	Flag	0
Bit3	Reserved	Reserved	R	-	-	0
Bit2	CH1_THERMAL	Channel1 THERMAL Alarm	R	Non-Flag	Flag	0
Bit1	Reserved	Reserved	R	-	-	0
Bit0	Reserved	Reserved	R	-	-	0

Byte15	Name	Control Function	Type	0	1	PWD
Bit7	Fault_Clear	Clear all the Alarm Flag	RW	No Clear	Clear	0
Bit6	One-Shot	One-Shot Temperature Conversion	RW	Disable Oneshot	Do OneShot	0
Bit5	DYN_AVE_EN	Enable Dynamic average	RW	Disable Dynamic Average	Enable Dynamic Average	0
Bit4	Conv. Rate 3		RW	See Detail From Convert Ratio Table		0
Bit3	Conv. Rate 2		RW			0
Bit2	Conv. Rate 1		RW			1
Bit1	Conv. Rate 0		RW			0
Bit0	Reserved	Reserved	RW	-	-	0

Byte16	Name	Control Function	Type	0	1	PWD
Bit7	TEMP <10:3>	MSB of Temperature	R	-	SIGN	0
Bit6			R		64	0
Bit5			R		32	0
Bit4			R		16	0
Bit3			R		8	0
Bit2			R		4	0
Bit1			R		2	0
Bit0			R		1	0

Byte17	Name	Control Function	Type	0	1	PWD
Bit7	Reserved	Reserved	R	-	-	0
Bit6	Reserved	Reserved	R	-	-	0
Bit5	Reserved	Reserved	R	-	-	0
Bit4	Reserved	Reserved	R	-	-	0
Bit3	Reserved	Reserved	R	-	-	0
Bit2	TEMP<2:0>	LSB of Temperature	R	-	0.5	0
Bit1			R		0.25	0
Bit0			R		0.125	0

Byte 18~21 Reserved Register

Byte22	Name	Control Function	Type	0	1	PWD
Bit7	TACH_MEASURE<7:0>	LSB of TACH Measurement	R	-	128	0
Bit6			R		64	0
Bit5			R		32	0
Bit4			R		16	0
Bit3			R		8	0
Bit2			R		4	0
Bit1			R		2	0
Bit0			R		1	0

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Byte23	Name	Control Function	Type	0	1	PWD
Bit7	Reserved	Reserved	R	-	-	0
Bit6	Reserved	Reserved	R	-	-	0
Bit5	Reserved	Reserved	R	-	-	0
Bit4	TACH_MEASURE<12:8>	MSB of TACH Measurement	R	-	4096	0
Bit3			R		2048	0
Bit2			R		1024	0
Bit1			R		512	0
Bit0			R		256	0

Byte24	Name	Control Function	Type	0	1	PWD
Bit7	Mode Select	Select the FAN Operating Mode	RW	00 - Direct Drive Mode	01 - Thermal Trigger Mode	1
Bit6			RW	10 - Dynamic PWM Mode	11 - Reserved	0
Bit5	Freq_Sel	Select the PWM frequency	RW	00 - 25KHz	01 - 22KHz	0
Bit4			RW	10 - 27KHz	11 - Reserved	0
Bit3	Edge	FAN Type Selection	RW	00 - 1Pole FAN	01 - 2 Poles FAN	0
Bit2			RW	10 - 3 Poles FAN	11 - 4 Poles FAN	1
Bit1	Error Range	TACH Detect Tolerant Error Rang	RW	00 - 0	01 - 32	0
Bit0			RW	10 - 64	11 - 128	1

Byte25	Name	Control Function	Type	0	1	PWD
Bit7	Spin-Up Time	The Time For Spin-Up	RW	00 - 250ms	01 - 500ms	0
Bit6			RW	10 - 1s	11 - 2s	1
Bit5	Spin-Up Duty	PWM Duty-Cycle For Spin-Up	RW	000 - 30%, 001 - 35%, 010 - 40%, 011 - 45%, 100 - 50%, 101 - 55%, 110 - 60%, 111 - 65%		1
Bit4			RW			1
Bit3			RW			0
Bit2	Spin-Up cnt	Time Out Times For Spin-Up	RW	00 - 3	01 - 4	0
Bit1			RW	10 - 5	11 - 6	1
Bit0	Reserved	Reserved	RW	-	-	0

Byte26	Name	Control Function	Type	0	1	PWD
Bit7	Duty_Cycle<10:3>	MSB of PWM Duty-Cycle Setting	RW	-	1	0
Bit6			RW		1/2	0
Bit5			RW		1/4	0
Bit4			RW		1/8	0
Bit3			RW		1/16	0
Bit2			RW		1/32	0
Bit1			RW		1/64	0
Bit0			RW		1/128	0

Byte27	Name	Control Function	Type	0	1	PWD
Bit7	Duty_Cycle<2:0>	LSB of PWM Duty-Cycle Setting	RW	-	1/256	0
Bit6			RW		1/512	0
Bit5			RW		1/1024	0
Bit4	Update Time	TACH Detect Update Time	RW	000 - 100ms, 001 - 200ms, 010 - 300ms, 011 - 400m, 100 - 500ms, 101 - 600ms, 110 - 700ms, 111 - 800ms		0
Bit3			RW			1
Bit2			RW			1
Bit1	T_Hys	Temperature Hysteresis For FAN's Trigger Point	RW	00 - 2C	01 - 5C	0
Bit0			RW	10 - 10C	11 - 15C	1

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Byte28	Name	Control Function	Type	0	1	PWD
Bit7	TL_FAN	First Temperature Trigger Point of FAN	RW	-	Reserved	0
Bit6			RW		64C	1
Bit5			RW		32C	1
Bit4			RW		16C	1
Bit3			RW		8C	1
Bit2			RW		4C	1
Bit1			RW		2C	1
Bit0			RW		1C	1

Byte29	Name	Control Function	Type	0	1	PWD
Bit7	TH_FAN	Second Temperature Trigger Point of FAN	RW	-	Reserved	0
Bit6			RW		64C	1
Bit5			RW		32C	1
Bit4			RW		16C	1
Bit3			RW		8C	1
Bit2			RW		4C	1
Bit1			RW		2C	1
Bit0			RW		1C	1

Byte30	Name	Control Function	Type	0	1	PWD
Bit7	TACH_MAX	The Maximum Limit of TACH Number	RW	-	4096	1
Bit6			RW		2048	1
Bit5			RW		1024	1
Bit4			RW		512	1
Bit3			RW		256	1
Bit2			RW		128	1
Bit1			RW		64	1
Bit0			RW		32	1

Byte31	Name	Control Function	Type	0	1	PWD
Bit7	TACH_MIN	The Minimum Limit of TACH Number	RW	-	512	0
Bit6			RW		256	0
Bit5			RW		128	0
Bit4			RW		64	0
Bit3			RW		32	0
Bit2			RW		16	0
Bit1			RW		8	0
Bit0			RW		4	0

Byte32	Name	Control Function	Type	0	1	PWD
Bit7	TACH_S1<12:5>	MSB TACH threshold of Static Mode(T>TL_FAN)	RW	-	4096	0
Bit6			RW		2048	0
Bit5			RW		1024	0
Bit4			RW		512	0
Bit3			RW		256	0
Bit2			RW		128	0
Bit1			RW		64	0
Bit0			RW		32	0

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Byte33	Name	Control Function	Type	0	1	PWD
Bit7	TACH_S1<4:0>	LSB TACH threshold of Static Mode(T>TL_FAN)	RW	-	16	0
Bit6			RW		8	0
Bit5			RW		4	0
Bit4			RW		2	0
Bit3			RW		1	0
Bit2	Reserved	Reserved	RW	-	-	0
Bit1	FAN_SEL	Temperature Selection For FAN	RW	00 - enable, 01~11 disable		1
Bit0			RW			0

Byte34	Name	Control Function	Type	0	1	PWD
Bit7	TACH_S2<12:5>	MSB TACH threshold of Static Mode(T>TH_FAN)	RW	-	4096	0
Bit6			RW		2048	0
Bit5			RW		1024	0
Bit4			RW		512	0
Bit3			RW		256	0
Bit2			RW		128	0
Bit1			RW		64	0
Bit0			RW		32	0

Byte35	Name	Control Function	Type	0	1	PWD
Bit7	TACH_S2<4:0>	LSB TACH threshold of Static Mode(T>TH_FAN)	RW	-	16	0
Bit6			RW		8	0
Bit5			RW		4	0
Bit4			RW		2	0
Bit3			RW		1	0
Bit2	FAN MASK	Mask Fan Fault	RW	0=normal	1=masked	0
Bit1	SEL_ALERT	Select the ALERT Source	RW	00 - ALERT=Temp-Sensor Alert	01 - ALERT=FAN Fault	0
Bit0			RW	10 - ALERT=Temp-Senso Alert or FAN Fault	10 - ALERT=Temp-Senso Alert and FAN Fault	0

Byte36	Name	Control Function	Type	0	1	PWD
Bit7	PWM Step	The PWM DutyCycle Incremental/Decremental Step	RW	-	128	0
Bit6			RW		64	0
Bit5			RW		32	0
Bit4			RW		16	0
Bit3			RW		8	1
Bit2			RW		4	0
Bit1			RW		2	0
Bit0			RW		1	0

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Byte37	Name	Control Function	Type	0	1	PWD
Bit7	Reserved	Reserved	R	-	-	0
Bit6	Reserved	Reserved	R	-	-	0
Bit5	Reserved	Reserved	R	-	-	0
Bit4	Reserved	Reserved	R	-	-	0
Bit3	Reserved	Reserved	R	-	-	0
Bit2	Reserved	Reserved	R	-	-	0
Bit1	FAN_Fault1	FAN TACH measurement is < Minimum limit (Too Fast)	R	Non-Flag	Flag	0
Bit0	FAN_Fault2	FAN TACH measurement is > Maximum limit (Too Slow)	R	Non-Flag	Flag	0

Byte38	Name	Control Function	Type	0	1	PWD
Bit7	TACH_AIM_OUT	Targeted TACH Readback	R	-	-	0
Bit6			R	-	-	0
Bit5			R	-	-	0
Bit4			R	-	-	0
Bit3			R	-	-	0
Bit2			R	-	-	0
Bit1			R	-	-	0
Bit0			R	-	-	0

Byte 39~ 40 Reserved Register

Byte41	Name	Control Function	Type	0	1	PWD
Bit7	STOP_27M_48M	Stop 27M_48M output	RW	Stopped	Run	1
Bit6	STOP_24M_48M	Stop 24M 48M output	RW	Stopped	Run	1
Bit5	EN_STOP25M_C	Enable pin for 25M_C after at PWRGD=0	RW	Free-Run	Stoppable	1
Bit4	EN_STOP25M_B	Enable pin for 25M_B after at PWRGD=0	RW	Free-Run	Stoppable	1
Bit3	EN_STOP25M_A	Enable pin for 25M_A after at PWRGD=0	RW	Free-Run	Stoppable	0
Bit2	STOP_25M_C	Stop 25M_C output	RW	Stopped	Run	1
Bit1	STOP_25M_B	Stop 25M_B output	RW	Stopped	Run	1
Bit0	STOP_25M_A	Stop 25M_A output	RW	Stopped	Run	1

Byte42	Name	Control Function	Type	0	1	PWD
Bit7	BYTE COUNT Register Bit[7:0]	MSB	RW	-	-	0
Bit6		-	RW	-	-	0
Bit5		-	RW	-	-	0
Bit4		-	RW	-	-	1
Bit3		-	RW	-	-	1
Bit2		-	RW	-	-	1
Bit1		-	RW	-	-	1
Bit0		LSB	RW	-	-	1

Byte 43 ~ Byte 46 Reserved Registers

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Byte47	Name	Control Function	Type	0	1	PWD
Bit7	REV_ID	Revision ID	RW	-	-	0
Bit6			RW	-	-	0
Bit5			RW	-	-	0
Bit4			RW	-	-	0
Bit3	VENDOR_ID	Vendor ID (IDT=0001)	RW	-	-	0
Bit2			RW	-	-	0
Bit1			RW	-	-	0
Bit0			RW	-	-	1

Byte 48 ~ Byte 63 Reserved Registers

Byte64	Name	Control Function	Type	0	1	PWD
Bit7	LCKBYPASSB	PLL Lock Bypassb	RW	Bypass	Not Bypas	1
Bit6	REF COUNT<6:0>	PLL M Counter	RW	-	-	0
Bit5			RW	-	-	0
Bit4			RW	-	-	1
Bit3			RW	-	-	1
Bit2			RW	-	-	0
Bit1			RW	-	-	0
Bit0			RW	-	-	1

Byte65	Name	Control Function	Type	0	1	PWD
Bit7	VCO COUNT<9:2>	PLL N COUNTER	RW	-	-	0
Bit6			RW	-	-	0
Bit5			RW	-	-	0
Bit4			RW	-	-	1
Bit3			RW	-	-	1
Bit2			RW	-	-	0
Bit1			RW	-	-	1
Bit0			RW	-	-	1

Byte 66 Reserved Register

Byte67	Name	Control Function	Type	0	1	PWD
Bit7	SL<1:0>(25MHzB)	25M_B Slew Rate Control	RW	00 = 0.5V/ns	01 = 1.0V/ns	0
Bit6			RW	10 = 1.0V/ns	11 = 1.5V/ns	1
Bit5	SL<1:0>(25MHzA)	25M_A Slew Rate Control	RW	00 = 1,0V/ns	01 = 1.5V/ns	0
Bit4			RW	10 = 1.5V/ns	11 = 2.0V/ns	1
Bit3	SL<1:0>(27MHz)	27M Slew Rate Control	RW	00 = 1,0V/ns	01 = 1.5V/ns	0
Bit2			RW	10 = 1.5V/ns	11 = 2.0V/ns	1
Bit1	SL<1:0>(24MHz)	24M Slew Rate Control	RW	00 = 1,0V/ns	01 = 1.5V/ns	0
Bit0			RW	10 = 1.5V/ns	11 = 2.0V/ns	1

All reserved bits and reserved bytes in this SMBus table should not be overwritten at any instance. Writing to these reserved bits and bytes may cause unexpected behavior. IDT does not warrant any application issue going forward if continuing to overwrite these reserve bits and bytes.

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Frequency Generator 32.768 kHz

Recommended 25MHz Quartz Crystal Specifications

SMD 25MHz AT cut crystal and maximum driver level at 100µW, for example TXC.

VBAT Battery Recommendations and Connection Considerations

Recommended to use coin cell battery CR2032, CR2025 or equivalent.

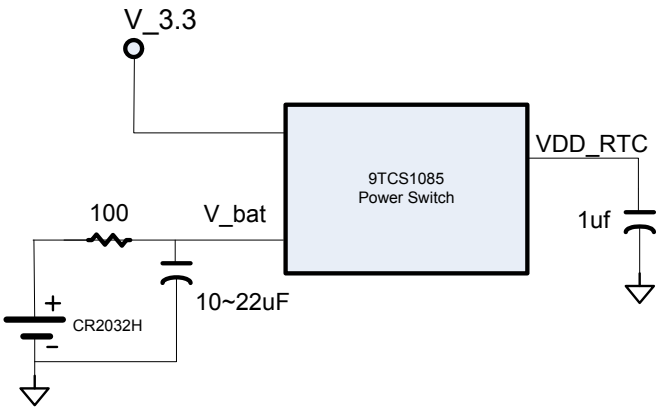
The normal coin cell battery storage capacity is 170 mAh to 220mAh and the average total RTC circuit current required 5uA, the battery life will be at least:

170,000 µAh / 5 µA = 34,000 hours = 3.88 years

The RTC circuit (PCH) usually consumes 3µA power, thus the 32.768kHz clock generator circuit needs be less than 2µA. The 9TCS1085 32.768kHz generator averaged operation current is less than 2µA.

The coin cell battery with 9TCS1085 VBAT power pin connection required a 100 ohm and 22µF ceramic capacitor current limitation and noise filtering. The RC needs to be added to the battery to limit the current spikes effects.

The VDD_RTC connect to the Intel ICH chip and the 9TCS1085 provide seamless power switching between main V_3.3 and V_bat.



32.768K Clocks Operation

The 9TCS1085 32.768K clock output operates in two modes:

1. When the system is not power ON, V_3.3 is not ready and 9TCS1085 is powered with the coin cell battery. The 32kHz comes from the DCO with the digital calibration to keep the accuracy.

2. After V_3.3 is ready, the 9TCS1085 creates a seamless switch power from V_bat to V_3.3 and the calibration will go to full speed: this will happen every 2~3ms to keep the accuracy and the 32K source will be switched to 25MHz oscillator with Fraction-N divider to get the 0ppm.

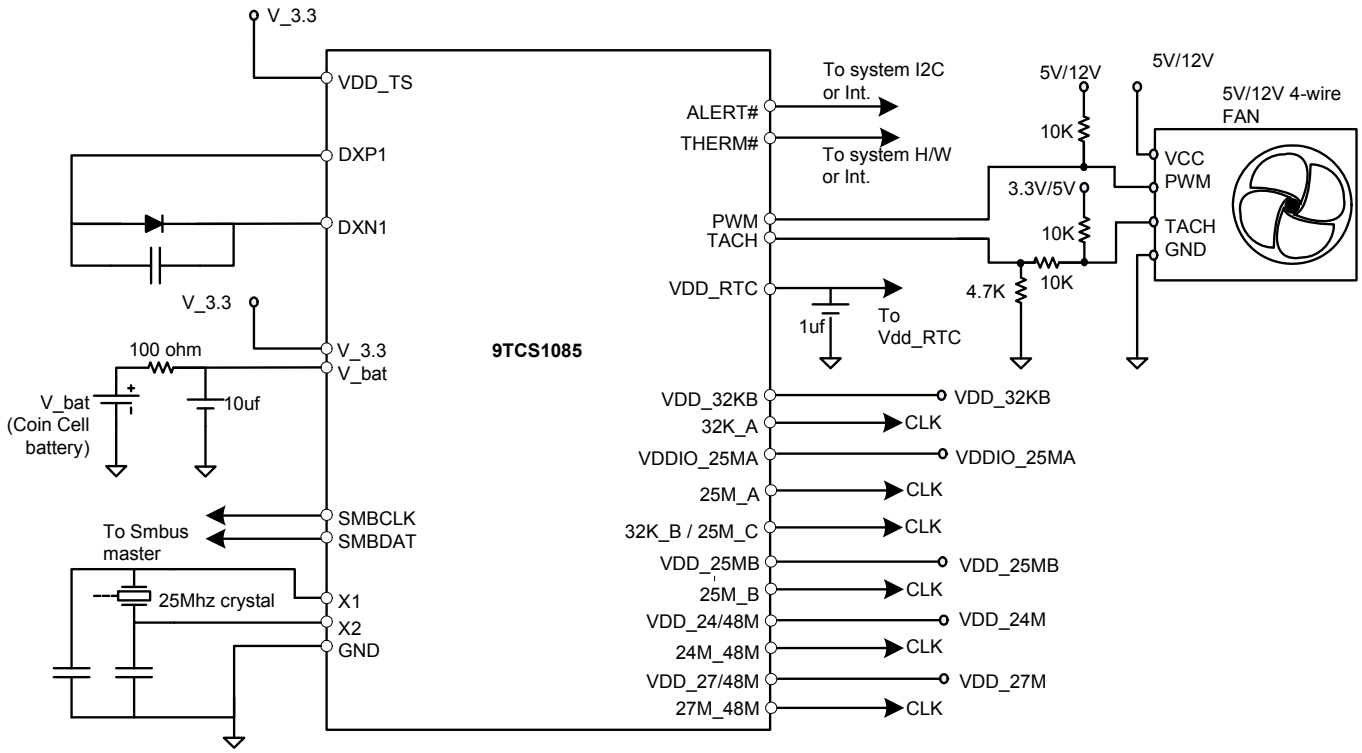
32.768K DCO uses a 25Mhz crystal oscillator for calibration reference, thus the 25MHz oscillator must be fine tuned in order to get the best 32.768kHz accuracy.

RTC Routing Guidelines

Single	race impedanc	Length	Notes
X1	50 ohm	6 inches	
X2	50 ohm	6 inches	

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Reference Schematic For VBAT and VDD_RTC

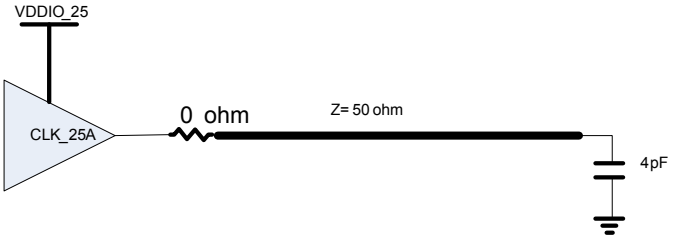


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Frequency Synthesizer – 24/48/27/25 MHz

The 9TCS1085 includes a low power PLL to generate 24/27/48 MHz clock outputs. The PLL uses an external 25MHz crystal for reference clock input, thus all 25MHz clock outputs are through a fanout buffer directly for optimal performance. Fine tuning on the external crystal cap load is required to get an accurate 25MHz reference clock.

25MHz_A Connection Recommendations



a. VDDIO_25A range is from 1.05V to 3.3V.

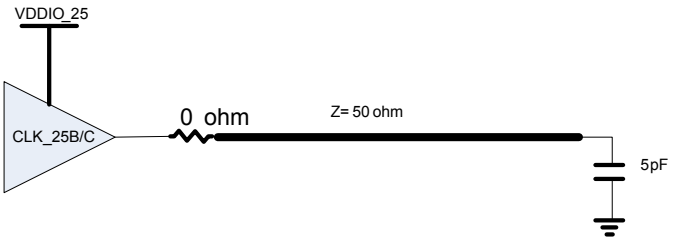
b. Optimize range is 1.05V to 1.5V.

c. Pull up strength is 50 ohm@VDDIO_25A=1.5V

d. Pull down strength is 50 ohm.

e. No on-board 33 ohm series resistor is required.

25MHz_B/C Connection Recommendations



a. VDD_25B/C range is from 1.05V to 3.3V.

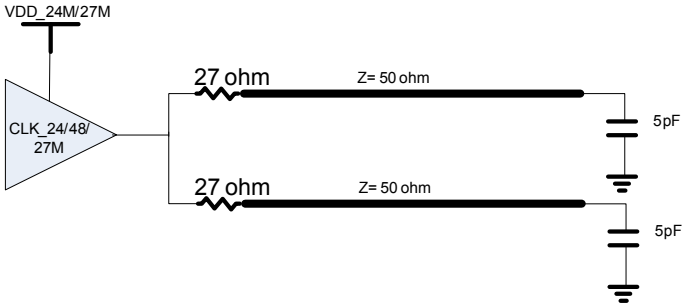
b. Optimized for 3.3V VDDIO.

c. Pull up strength is 50 ohm@VDD_25B/C=3.3V

d. Pull down strength is 50 ohm.

e. No on-board 33 ohm series resistor is required.

24/27/48MHz Connection Recommendations



a. Default 2X push-pull IO drive strength for 24/48/27MHz.

b. On board 27 ohm series resistor for each path.

c. Rising/falling slew rate: 1v/ns~4v/ns

d. 2 bits (3 steps) I2C for the Slew Rate.

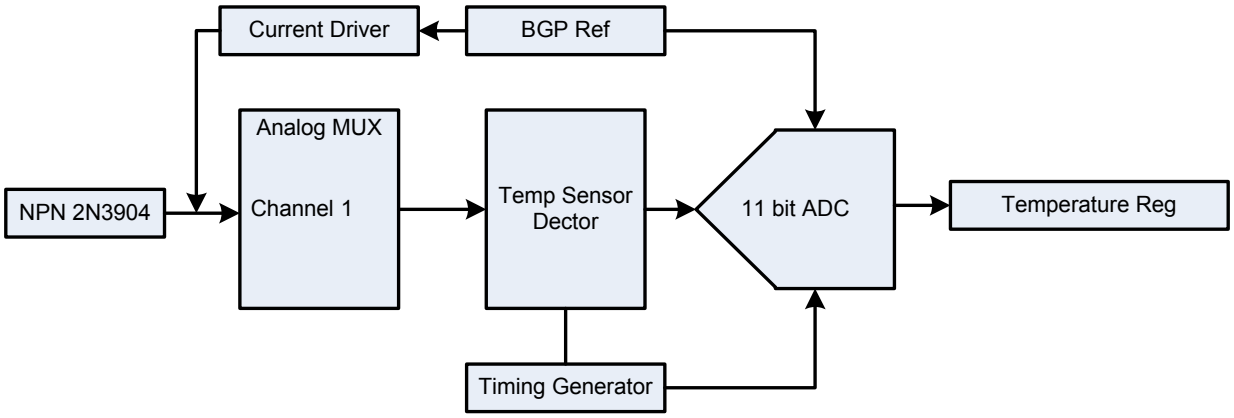
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Thermal Sensor

The thermal sensor in the 9TCS1085 is a low power and highly accurate temperature sensor. It is optimized to operate between 60°C to 100°C with an external thermal diode connection input. There are diode faults and temperature alerts for the thermal sensor; Moreover, the thermal sensor has the capability to go into standby mode for power savings.

The temperature sensor's analog to digital converter (ADC) has 11 bits of resolution. One LSB is equal to 0.125°C. The accuracy of the temperature sensor is ±1°C between 60°C to 100°C.

The 9TCS1085 temperature sensor has the ability to cancel the series resistance on the remote diode inputs. Parasitic resistances to the DXP and DXN inputs seen in series with the remote diode are caused by PCB trace resistance along with the overall length, bulk parasitic resistance in the remote temperature transistor junctions, and series resistance in the CPU. This resistance appears as a temperature offset in the thermal sensor measurement and is approximately +0.7°C per Ohm. The 9TCS1085 has the ability to cancel up to 100Ω of series resistance.



The thermal sensor in 9TCS1085 outputs the measured temperature from a beta compensated temperature reading from an external diode. The temperature sensor architecture uses an on-chip ADC as shown to convert the analog temperature into an 11-bit digital code. Using averaging techniques along with the ADC architecture allows accurate temperature measurements. The ability to have programmable conversion rates and adjustable averaging schemes allow the user the flexibility to balance accuracy versus conversion speed per the system requirements.

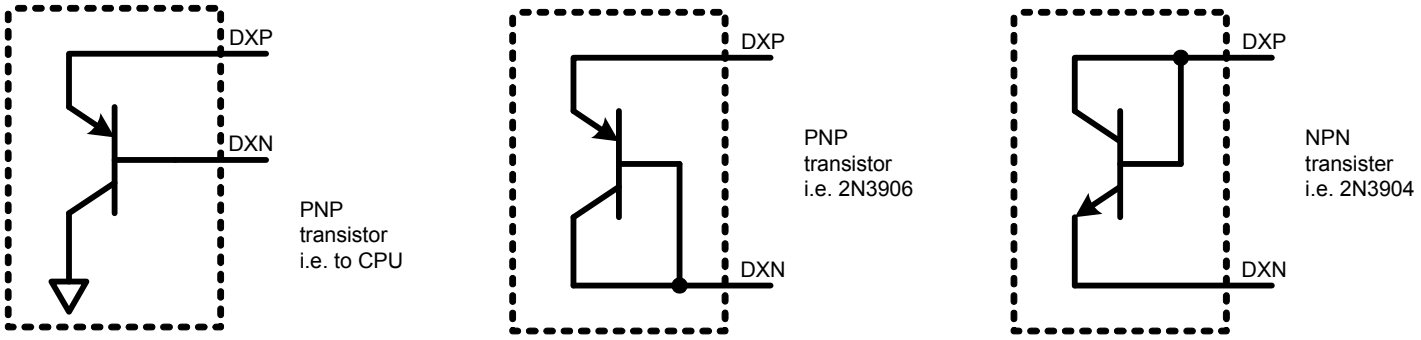
The temperature measurement relies on the characteristics of a semiconductor junction operating at a fixed current level. Forcing a fixed current through the temperature diodes and detecting the changes in VBE, the forward voltage of the diode, the temperature proportionality can be determined.

External Thermal Diode Selection

The 9TCS1085 supports the following temperature diodes:

- Typical remote substrate transistor (i.e. CPU substrate PNP intrinsic diode)
- Discrete PNP transistor diode (i.e. 2N3906)
- Discrete NPN transistor diode (i.e. 2N3904)

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When the thermal sensor is used in a noisy environment, a capacitor can be connected across DXP and DXN to provide some noise filtering capabilities. However, large capacitances affect the accuracy of the temperature measurement. A maximum capacitance of 300pF can be used to help mitigate the noise.

Thermal Diode Fault Conditions

9TCS1085 has the ability to detect an open or a short condition for each temperature sensor diode. An external diode fault is defined as one of the following:

- An open between DXP and DXN
- A short from VDD to DXP
- A short from VDD to DXN

The diode fault monitoring is enabled at the start of every temperature measurement. When an external diode fault is detected, the ALERT# pin asserts and the temperature data reads 00h in the MSB and LSB of the corresponding temperature registers:

- DX1 MSB - byte[17], bit[2:0]
- DX1 LSB - byte[16], bit[7:0]

During the fault condition, byte[13], bit[1] or bit[0], will be set depending on the channel that has the fault. Bit[1] corresponds to DX1, and furthermore, an open/short fault flag will be set in register byte[14], bit[4].

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Temperature Threshold Alerts

Through register writes, the high and low temperature limits can be set such that it will trigger an alert. This alert can be monitored through the registers or can be sent to the ALERT# pin. Each channel has its own programmable register to set the thresholds as follows:

(1) High Temperature Alert (default 127°C)

Byte[2:0], Bit[7:0]	Temperature
Bit[7]	Sign Bit
Bit[6]	64°C
Bit[5]	32°C
Bit[4]	16°C
Bit[3]	8°C
Bit[2]	4°C
Bit[1]	2°C
Bit[0]	1°C

Where byte[0] is the high temperature alert for DX1.

(2) Low Temperature Alert (default 127°C)

Byte[5:3], Bit[7:0]	Temperature
Bit[7]	Sign Bit
Bit[6]	64°C
Bit[5]	32°C
Bit[4]	16°C
Bit[3]	8°C
Bit[2]	4°C
Bit[1]	2°C
Bit[0]	1°C

Where byte[3] is the low alert for DX1, byte[4] is for DX2.

Temperature Threshold Alert Status

When a temperature threshold alert is activated, a status indicator bit is also set. Register byte[14], bit[6:5] will be set depending on the high or low alert. Bit[6] is the high and bit[5] is the low alert flag. To clear the alert, register byte[15], bit[7] needs to be written with a "1". Writing this bit will also clear the critical thermal warnings.

Temperature Threshold ALERT# Pin

The temperature threshold alerts are sent to the ALERT# pin. To mask this alert being sent to the ALERT# pin, set register byte[12], bit[7] to logic 1.

Consecutive Alerts

The number of temperature threshold alerts before the assertion of the ALERT# pin can be set by the user through register byte[6], bit[3:2] as follows:

Byte[6], Bit[3:2]	Number of Alert Events
[00] (default)	1
[01]	2
[10]	3
[11]	4

Temperature Threshold Alert Alarm Register

All three temperature channels have a readable registers, byte[13], bit[7:2] that is set when a temperature threshold alert has occurred. Bit[3:2] is for temperature high and low thresholds.

Critical Thermal Warnings

The 9TCS1085 will have register programmable critical thermal threshold warnings for all three temperature sensor channels. Similar to the temperature threshold alerts, the critical high temperatures can be set such that a warning can be dispatched to the THERM# pin and the readable registers. The thermal warnings also have programmable hysteresis. Each channel has its own programmable register to set the thresholds as follows:

(1) Critical Thermal Warning (default 127°C)

Byte[9:7], Bit[6:0]	Temperature
Bit[6]	64°C
Bit[5]	32°C
Bit[4]	16°C
Bit[3]	8°C
Bit[2]	4°C
Bit[1]	2°C
Bit[0]	1°C

Where byte[7] is the critical thermal warning for DX1.

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(2) Critical Thermal Warning Temperature Hysteresis (default 4°C)

Byte[12], Bit[4:0]	Temperature
Bit[4]	16°C
Bit[3]	8°C
Bit[2] (default)	4°C
Bit[1]	2°C
Bit[0]	1°C

Critical Thermal Warning Status

When a critical warning is activated, a status indicator bit is also set. Register byte[14], bit[2] will be set when the critical event happens.

Critical Thermal Warning THERM# Pin

The critical thermal warnings are sent to the THERM# pin and requires a system register write to byte[15], bit[7] to reset. This fault clear I2C write will also clear the temperature threshold alerts

Active/Standby Mode

The thermal sensor has two modes in the temperature conversion process:

(1) Active mode – In this mode the ADC will have a selectable conversion rate for the temperature sensing.

(2) Standby mode – The system will command via I2C the 9TCS1085 to sample the temperature sensors. Once the temperature reading from the ADC is updated, the temperature sensor will be on stand-by awaiting the next system request.

Register byte[15], bit[6] controls whether the thermal sensor is in active or standby mode.

The conversion rate programmable register detail is as follows:

Byte[17], Bit[4:1]	Conversion Rate
[0000]	16/sec *
[0001]	8/sec **
[0010] (default)	4/sec
[0011]	2/sec
[0100]	1/sec
[0101]	1/2 sec
[0110]	1/4 sec
[0111]	1/8 sec
[1000]	1/16 sec
[1001]	1/32 sec
[1010]	1/64 sec

* Valid when only one temperature sensor channel is used.

** Valid when the number of temperature sensor channel is less than three.

The thermal sensor architecture has dynamic averaging to smooth out the temperature conversion readings. To select the number of temperature reading averages requires the dynamic averaging function to be enabled, register byte[15], bit[5]. The number of averages is then selected as follows:

Byte[6], Bit[1:0]	Average the ADC Temperature
[00]	1
[01]	4
[10]	8
[11]	16

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Fan Controller

Fan Controller Description

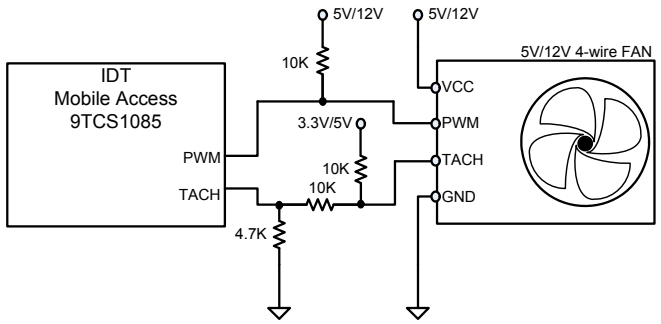
The fan driver for the 9TCS1085 controls a 4-wire, 12V or 5V, multiple pole DC fan. The fan controller has three modes of operation: (1) Direct drive, (2) Thermal trigger, and (3) Dynamic PWM. All modes have register programmability for the user to set the desired fan speed and necessary parameters. The controller is also capable of detecting stalled fans and upon detection will set the appropriate alerts. The 9TCS1085 also has user configuration registers to adjust both the ramp-rate and the spin-up routine to accommodate different fan start up requirements.

The fan controller uses the input from the external diode connections. The 9TCS1085 fan controller can be set to run a user specified fan speed. In this mode the tachometer signal from the fan will be ignored. In thermal trigger mode, the user specifies the temperature thresholds, the temperature threshold hysteresis, and the corresponding fan speed (fan tachometer target) for the different temperature zones defined by the thresholds. The controller will then run the fan at the specified fixed fan speed settings depending on the temperature from the sensors. In dynamic PWM mode, the fan controller will adjust the PWM duty cycle to maintain the system defined fan speed. In this mode, the system reads a temperature sensor and the corresponding fan speed, tachometer reading. The system will then determine and update the 9TCS1085 directly by writing the accessible registers byte 32 and byte 33. 9TCS1085 will then adjust the PWM to achieve the desired system fan speed.

The PWM has ten bits of duty cycle resolution with a 25kHz frequency. The PWM frequency is selectable between 22, 25, and 27kHz.

The 9TCS1085 includes hardware programmable temperature limits and dedicated system shutdown output for thermal protection.

Fan Controller System Diagram (Schematic Example)



Fan Selection Detail

The 9TCS1085 fan controller will control 5V - 12V Brushless DC fans. The fans need to be 4-wire fans and can have one to four poles. The number of fan poles is specified in Register byte[24], bit[3:2]. A 2-pole fan is the default.

Byte[24], Bit[3:2]	Fan Poles
[00]	1
[01] (default)	2
[10]	3
[11]	4

Modes of Operation

The 9TCS1085 fan controller has three user selectable methods to control the fan speed. The default fan speed control mode is Thermal Trigger mode. The modes are selected by writing the I2C register byte[24], bit[7:6] as follows:

Fan Controller Modes	Byte[24], Bit[7:6]
Direct Drive	[00]
Thermal Trigger	[01]
Dynamic PWM (default)	[10]

The PWM frequency can be set by writing register byte[24], bit[5:4] as follows:

PWM Frequency	Duty Cycle Resolution [# bits]	Byte[24], Bit[5:4]
25kHz (default)	10	00
22kHz	11	01
27kHz	9	10

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Direct Drive Mode

In Direct Drive Mode, the fan speed is directly controlled by setting a fixed PWM duty cycle. After a proper fan speed spin-up, the tachometer signal will be ignored and the 9TCS1085 will output the fixed programmed PWM duty cycle to the fan.

To operate in direct drive mode, Register byte[24], bit[7:6] = [00].

The duty cycle is selectable through registers by writing byte[26], bit[7:0] and byte[27], bit[7:5] as follows:

Byte[26], Bit[7:0]	Logic "1", Selects Duty Cycle
Bit[7]	1
Bit[6]	1/2
Bit[5]	1/4
Bit[4]	1/8
Bit[3]	1/16
Bit[2]	1/32
Bit[1]	1/64
Bit[0]	1/128

Byte[27], Bit[7:5]	Logic "1", Selects Duty Cycle
Bit[7]	1/256
Bit[6]	1/512
Bit[5]	1/1024

It is important to also set the required fan spin-up specifics for proper use. The 9TCS1085 after completion of the fan spin-up routine will then put out the correct programmed PWM duty cycle.

Thermal Trigger Mode

In this mode the 9TCS1085 fan speed controller is programmed to run at different fan speeds. The 9TCS1085 will monitor the fan tachometer and depending on the temperature from a thermal sensor diode and the pre-programmed temperature settings, the 9TCS1085 will adjust the fan speed to the targeted tachometer settings.

Register byte[24], bit[7:6] = [01] will put 9TCS1085 into thermal trigger mode.

Temperature Sensor

The temperature can be set to read from the external thermal sensors; it is selected by byte33b[1:0]=00.

FAN_CH_SEL - byte[33], bit[1:0]

Byte[33], bit[1:0]	Temperature Sensor Enable/Disable
[00]	00=ON, 01~11=disable

Tachometer Update

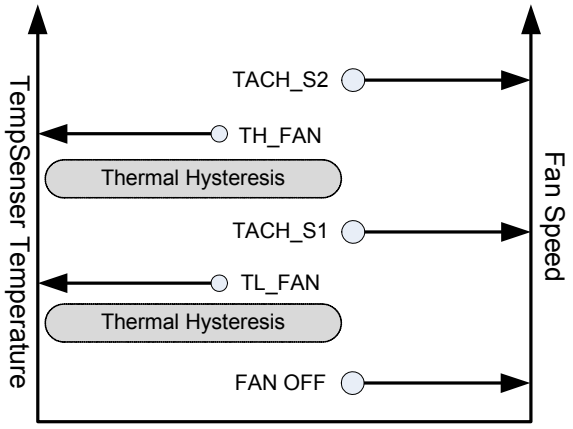
The tachometer reading can be updated at a rate of 700msec up to 100msecs. Tachometer Update Time, byte[27], bit[4:2]

Byte[27], bit[4:2]	Tachometer Update Time
[000]	100 msec
[001]	200 msec
[010]	300 msec
[011] (default)	400 msec
[100]	500 msec
[101]	600 msec
[110]	700 msec
[111]	800 msec

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Example of Thermal Trigger Mode Setup

The figure below shows how the programmable thresholds relate to the fan speed settings.



From the figure above, it can be seen that the fan speed will adjust between the tachometer settings TACH_S1 and TACH_S2 given the temperature from the thermal sensor. The temperature thresholds are set by TH_FAN and TL_FAN along with the temperature hysteresis, T_HYS. In this mode, the fan will have active fault condition monitoring along with fan spin-up control. The rate at which the fan will speed up or slow down, going from one TACH setting to the other, can be programmed by the user. Lastly, the fan speed tolerance can also be selectable via registers.

To set up the fan speed controller in Thermal Trigger Mode, the following registers will need to be programmed.

(1) Temperature Thresholds:

a. TL_FAN - byte[28], bit[6:0] (default 127°C)

Byte[28], Bit[7:0]	Logic "1", Selects Temp Threshold
Bit[7]	—
Bit[6]	64°C
Bit[5]	32°C
Bit[4]	16°C
Bit[3]	8°C
Bit[2]	4°C
Bit[1]	2°C
Bit[0]	1°C

b. TH_FAN - byte[29], bit[6:0] (default 127°C)

Byte[29], Bit[7:0]	Logic "1", Selects Temp Threshold
Bit[7]	—
Bit[6]	64°C
Bit[5]	32°C
Bit[4]	16°C
Bit[3]	8°C
Bit[2]	4°C
Bit[1]	2°C
Bit[0]	1°C

To set TL_FAN and TH_FAN a logic "1" is written into the proper register. For example, to get 70°C, a "1" would be written for Bit[6], Bit[2], and Bit[1].

(2) Temperature Hysteresis, T_HYS, byte[27], bit[1:0]:

Byte[27], bit[1:0]	Temperature Threshold Hysteresis
[00]	2°C
[01]	5°C
[10]	10°C
[11] (default)	15°C

(3) Tachometer Targets:

a. TACH_S1 - byte[32], bit[7:0] and byte[33], bit[7:3]

Byte[32], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	4096
Bit[6]	2048
Bit[5]	1024
Bit[4]	512
Bit[3]	256
Bit[2]	128
Bit[1]	64
Bit[0]	32

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Byte[33], bit[7:3]	Logic "1" selects Tachometer Reading
Bit[7]	16
Bit[6]	8
Bit[5]	4
Bit[4]	2
Bit[3]	1

b. TACH_S2 - byte[34], bit[7:0] and byte[35], bit[7:3]

Byte[34], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	4096
Bit[6]	2048
Bit[5]	1024
Bit[4]	512
Bit[3]	256
Bit[2]	128
Bit[1]	64
Bit[0]	32

Byte[35], bit[7:3]	Logic "1" selects Tachometer Reading
Bit[7]	16
Bit[6]	8
Bit[5]	4
Bit[4	2
Bit[3]	1

The TACH_S1/S2 is set using the following RPM formula:

$$RPM = 2 \times F_{sample} \times \frac{60}{TACH_\text{Re}ading} \quad \textbf{(Formula 1)}$$

where: RPM - fan revolution per minute
F_{sample} - 25kHz sample internal clock sample rate
TACH_Reading - user programmable registers Byte[32] through Byte[35]

(4) To Set the minimum and maximum fan speed, use the RPM formula, "Formula 1".

a. TACH_MIN - byte[31], bit[7:0]

Byte[31], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	512
Bit[6]	256
Bit[5]	128
Bit[4]	64
Bit[3]	32
Bit[2]	16
Bit[1]	8
Bit[0]	4

b. TACH_MAX - byte[30, bit[7:0]

Byte[30], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	4096
Bit[6]	2048
Bit[5]	1024
Bit[4]	512
Bit[3]	256
Bit[2]	128
Bit[1]	64
Bit[0]	32

(5) To adjust the rate at which the fan speed will transition from one TACH setting to the other, the RPM equation, "Formula 1" is again applied to determine the incremental or decremental fan speed step size.

Tachometer PWM Step Control - byte[36], bit[7:0]

Byte[36], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	128
Bit[6]	64
Bit[5]	32
Bit[4]	16
Bit[3]	8
Bit[2]	4
Bit[1]	2
Bit[0]	1

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Spin-up

In this mode the fan controller will also have spin-up control capabilities. At any time the fan attempts to go from a zero RPM to a higher fan speed, the fan will always go through the proper spin-up routine. The time allotted for fan spin-up as well as the spin-up PWM duty cycle can be adjusted via registers by writing byte[25], bit[7:3] as follows:

Spin-up Time - byte[25], bit[7:6]

Byte[25], bit[7:6]	Spin-up Time
Bit[7:6] = [00]	250msec
Bit[7:6] = [01] (default)	500msec
Bit[7:6] = [10]	1sec
Bit[7:6] = [11]	2sec

Spin-up PWM duty cycle - byte[25], bit[5:3]

Byte[25], bit[5:3]	Spin-up PWM duty cycle
Bit[5:3] = [000]	30%
Bit[5:3] = [001]	35%
Bit[5:3] = [010]	40%
Bit[5:3] = [011]	45%
Bit[5:3] = [100]	50%
Bit[5:3] = [101]	55%
Bit[5:3] = [110] (default)	60%
Bit[5:3] = [111]	65%

Dynamic PWM Mode

The 9TCS1085 in this mode will be directed by the system via registers as to the target RPM by which the fan speed should be running. The system will read a temperature sensor along with the fan tachometer information and make the determination as to what the nominal fan speed should be. This information is fed back to the 9TCS1085 via register writes. 9TCS1085 will comply and attempt to run the fan at the requested speed.

To put the 9TCS1085 in Dynamic PWM mode register byte[24], bit[7:6] = [10]

The system will poll byte[22], bit[7:0], and byte[23], bit[4:0] for the TACH reading which will correlate to the current fan speed by the RPM equation, “Formula 1”.

Byte[22], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	128
Bit[6]	64
Bit[5]	32
Bit[4]	16
Bit[3]	8
Bit[2]	4
Bit[1]	2
Bit[0]	1

Byte[23], bit[4:0]	Logic "1" selects Tachometer Reading
Bit[7]	4096
Bit[6]	2048
Bit[5]	1024
Bit[4]	512
Bit[3]	256

The system can read the temperature sensor diodes from the 9TCS1085 or from any sensor available to the system to determine the necessary adjustments to the fan speed.

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System Direct Tachometer Control

The system will directly write to register byte[32], bit[7:0] and byte[33], bit[7:3] a desired TACH setting.

Byte[32], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	4096
Bit[6]	2048
Bit[5]	1024
Bit[4]	512
Bit[3]	256
Bit[2]	128
Bit[1]	64
Bit[0]	32

Byte[33], bit[7:3]	Logic "1" selects Tachometer Reading
Bit[7]	16
Bit[6]	8
Bit[5]	4
Bit[4]	2
Bit[3]	1

The tachometer setting is related to the fan speed by the RPM equation, “Formula 1”.

Setting Minimum and Maximum Tachometer RPM

The minimum and maximum tachometer settings can be set for the fan faults.

a. TACH_MIN - byte[31], bit[7:0]

Byte[31], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	512
Bit[6]	256
Bit[5]	128
Bit[4]	64
Bit[3]	32
Bit[2]	16
Bit[1]	8
Bit[0]	4

b. TACH_MAX - byte[30, bit[7:0]

Byte[30], bit[7:0]	Logic "1" selects Tachometer Reading
Bit[7]	4096
Bit[6]	2048
Bit[5]	1024
Bit[4]	512
Bit[3]	256
Bit[2]	128
Bit[1]	64
Bit[0]	32

Fan Fault Conditions

The fan fault conditions will be activated and reported if the minimum or maximum fan speed is detected. During a FAULT1, maximum fan speed, 9TCS1085 will stop the fan and then wait for the FAULT1 flag to be cleared. For a FAULT2 condition, stalled fan, 9TCS1085 will go through the spin-up procedure to try to start the fan. The number of attempts to try to restart the fan is programmable. The fan fault conditions are reported via register on byte[37], bit[1;0].

Fan Fault Conditions

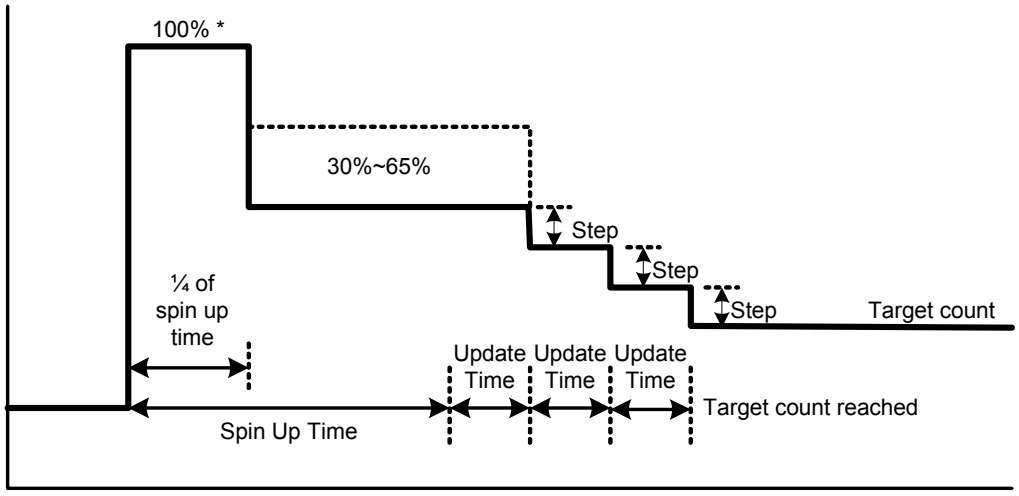
Byte[37], bit[1:0]	Logic "1" = FAULT CONDITION
Bit[1]	Fault1 - Fan speed too fast
Bit[0]	Fault2 - Fan speed too slow

The number of times for spin-up retries:

Byte[25], bit[2:1]	Number of Spin-up Attempts
[00]	3
[01] (default)	4
[10]	5
[11]	6

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Spin-up Details



1. The spin-up time can be specified in register byte[25], bit[7:6].

Spin-up Time - byte[25], bit[7:6]

Byte[25], bit[7:6]	Spin-up Time
Bit[7:6] = [00]	250msec
Bit[7:6] = [01] (default)	500msec
Bit[7:6] = [10]	1sec
Bit[7:6] = [11]	2sec

2. During spin-up, the PWM duty cycle can be set to 100% for one quarter of the total spin-up time by register byte[25], bit[0].

3. The next three quarters of the spin-up time, the PWM duty cycle is set by register[25], bit[5:3].

Spin-up PWM duty cycle - byte[25], bit[5:3]

Byte[25], bit[5:3]	Spin-up PWM duty cycle
Bit[5:3] = [000]	30%
Bit[5:3] = [001]	35%
Bit[5:3] = [010]	40%
Bit[5:3] = [011]	45%
Bit[5:3] = [100]	50%
Bit[5:3] = [101]	55%
Bit[5:3] = [110] (default)	60%
Bit[5:3] = [111]	65%

Fan Controller Temperature Diode Sensor

The fan controller can use either one of the three channels for temperature sensing. To specify which temperature sensor is used for the fan controller, register byte[33], bit[1:0].

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Marking Diagram (NLG32)



Notes:

1. "######" is the lot number.
2. YYWW is the last two digits of the year and week that the part was assembled.
3. "$$$" is the assembly mark code..
4. "B" at the end of the part number is the device revision desigantor; does not correlate with the datasheet revision.
5. Bottom marking: country of origin if not USA.

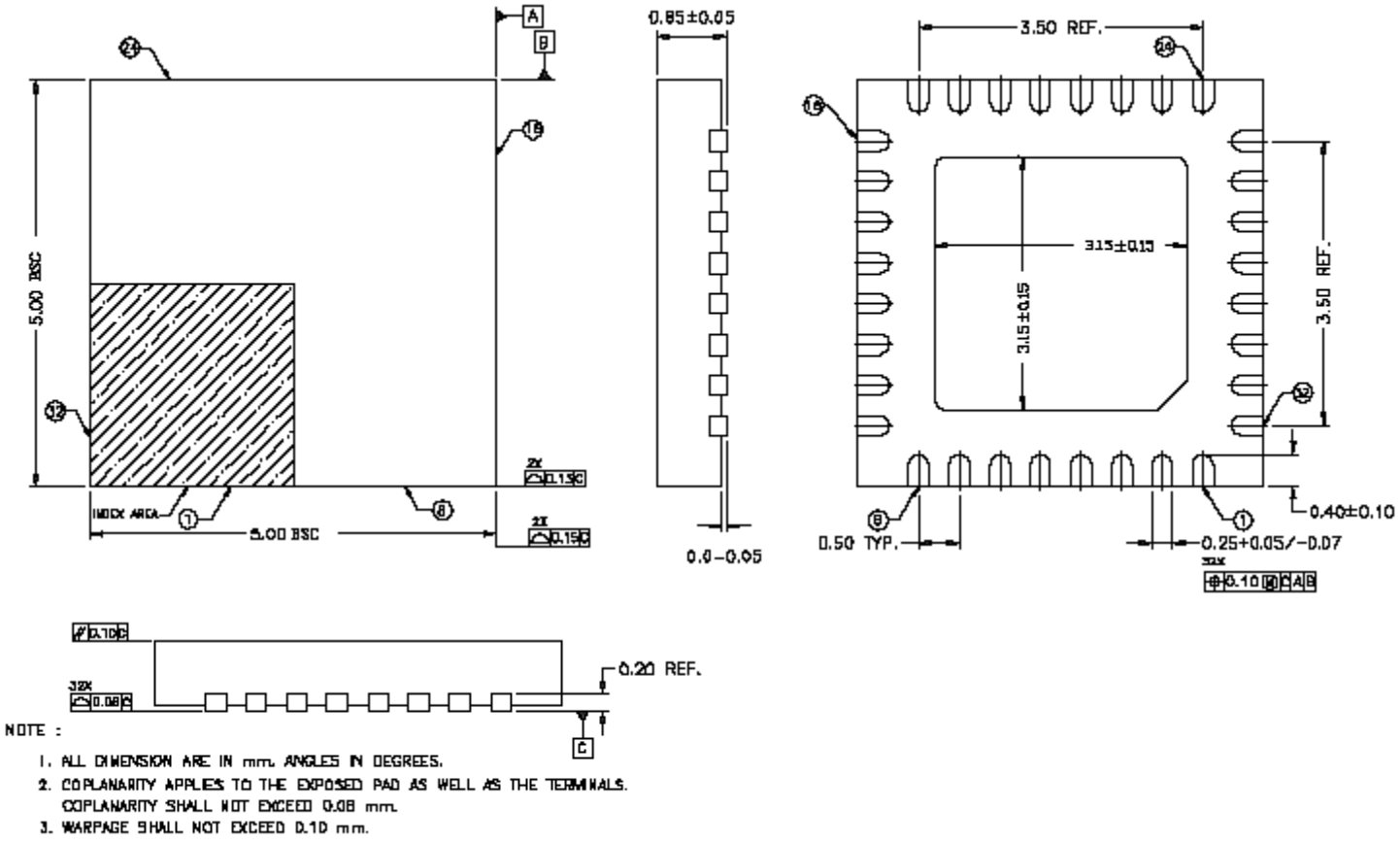
Thermal Characteristics 32-pin VFQFPN

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		34		°C/W
	θ_{JA}	1 m/s air flow		29		°C/W
	θ_{JA}	3 m/s air flow		27		°C/W
Thermal Resistance Junction to Case	θ_{JC}			32		°C/W

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Package Outline and Package Dimensions (32-pin VFQFPN, 0.50mm pitch)

Package dimensions are kept current with JEDEC Publication No. 95



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
9TCS1085BNLG	see page 36	Trays	32-pin VFQFPN	0 to +70° C
9TCS1085BNLG8		Tape and Reel	32-pin VFQFPN	0 to +70° C

"G" after the two-letter package code are the Pb-Free configuration and are RoHS compliant.

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(Rev.1.0 Mar 2020)

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